NSN 5961-00-999-4561

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-999-4561

Inclosure Material:

Metal

Overall Length:

1.564 inches

Overall Height:

0.400 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 10.0 emitter to base voltage, static, collector open and 60.0 breakdown

voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

6.00 amperes source cutoff current and 3.00 amperes source cutoff current

Power Rating Per Characteristic:

429.0 milliwatts small-signal input power, common-collector absolute

Transfer Ratio:

75.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

80.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0